PSMN034-100PS

N-channel 100 V 34.5 mΩ standard level MOSFET in TO220.

Rev. 02 — 1 March 2010 **Objective data sheet**

1. Product profile

1.1 General description

Standard level N-channel MOSFET in TO220 package qualified to 175C. This product is designed and qualified for use in a wide range of industrial, communications and domestic equipment.

1.2 Features and benefits

- High efficiency due to low switching and conduction losses
- Suitable for standard level gate drive

1.3 Applications

- DC-to-DC converters
- Load switching
- Motor control
- Server power supplies

1.4 Quick reference data

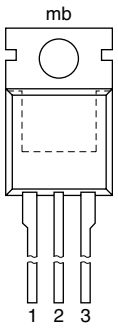
Table 1. Quick reference

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{DS}	drain-source voltage	$T_j \geq 25$ °C; $T_j \leq 175$ °C	-	-	100	V
I_D	drain current	$T_{mb} = 25$ °C; $V_{GS} = 10$ V; see Figure 1	-	-	32	A
P_{tot}	total power dissipation	$T_{mb} = 25$ °C; see Figure 2	-	-	86	W
T_j	junction temperature		-55	-	175	°C
Avalanche ruggedness						
$E_{DS(AL)S}$	non-repetitive drain-source avalanche energy	$V_{GS} = 10$ V; $T_{j(init)} = 25$ °C; $I_D = 32$ A; $V_{sup} \leq 100$ V; unclamped; $R_{GS} = 50$ Ω	-	-	42	mJ
Dynamic characteristics						
Q_{GD}	gate-drain charge	$V_{GS} = 10$ V; $I_D = 15$ A; $V_{DS} = 50$ V; see Figure 12 and 13	-	6.9	-	nC
$Q_{G(tot)}$	total gate charge		-	23.8	-	nC
Static characteristics						
R_{DSon}	drain-source on-state resistance	$V_{GS} = 10$ V; $I_D = 15$ A; $T_j = 100$ °C; see Figure 11	-	-	62	mΩ
		$V_{GS} = 10$ V; $I_D = 15$ A; $T_j = 25$ °C; see Figure 16	-	29.3	34.5	mΩ

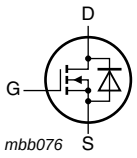
2. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate		
2	D	drain		
3	S	source		
mb	D	mounting base; connected to drain		



SOT78 (TO-220AB)



3. Ordering information

Table 3. Ordering information

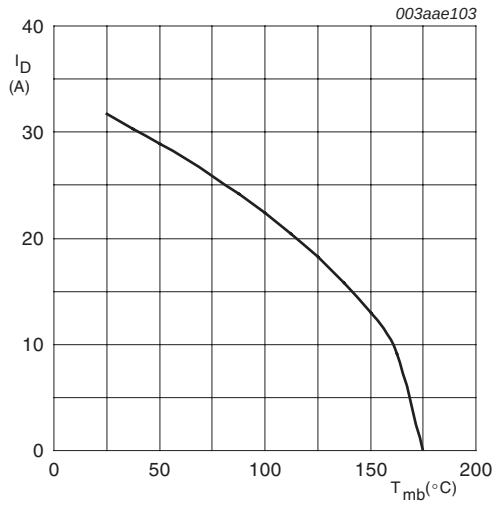
Type number	Package		
	Name	Description	Version
PSMN034-100PS	TO-220AB	plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB	SOT78

4. Limiting values

Table 4. Limiting values

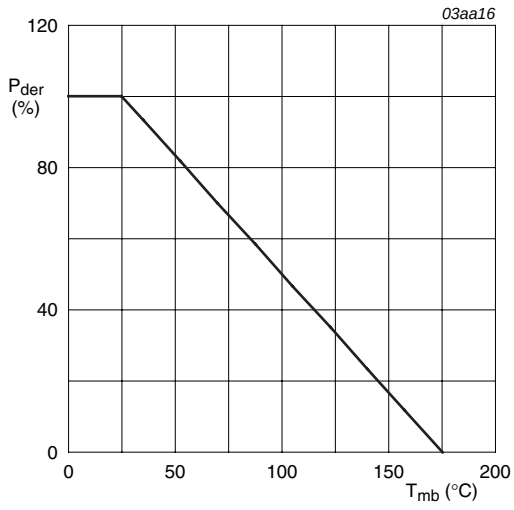
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage	$T_j \geq 25$ °C; $T_j \leq 175$ °C	-	100	V
V_{DGR}	drain-gate voltage	$T_j \leq 175$ °C; $T_j \geq 25$ °C; $R_{GS} = 20$ kΩ	-	100	V
V_{GS}	gate-source voltage		-20	20	V
I_D	drain current	$V_{GS} = 10$ V; $T_{mb} = 100$ °C; see Figure 1	-	22	A
		$V_{GS} = 10$ V; $T_{mb} = 25$ °C; see Figure 1	-	32	A
I_{DM}	peak drain current	$t_p \leq 10$ µs; pulsed; $T_{mb} = 25$ °C; see Figure 3	-	127	A
P_{tot}	total power dissipation	$T_{mb} = 25$ °C; see Figure 2	-	86	W
T_{stg}	storage temperature		-55	175	°C
T_j	junction temperature		-55	175	°C
$T_{sld(M)}$	peak soldering temperature		-	260	°C
Source-drain diode					
I_S	source current	$T_{mb} = 25$ °C	-	32	A
I_{SM}	peak source current	$t_p \leq 10$ µs; pulsed; $T_{mb} = 25$ °C	-	127	A
Avalanche ruggedness					
$E_{DS(AL)S}$	non-repetitive drain-source avalanche energy	$V_{GS} = 10$ V; $T_{j(init)} = 25$ °C; $I_D = 32$ A; $V_{sup} \leq 100$ V; unclamped; $R_{GS} = 50$ Ω	-	42	mJ



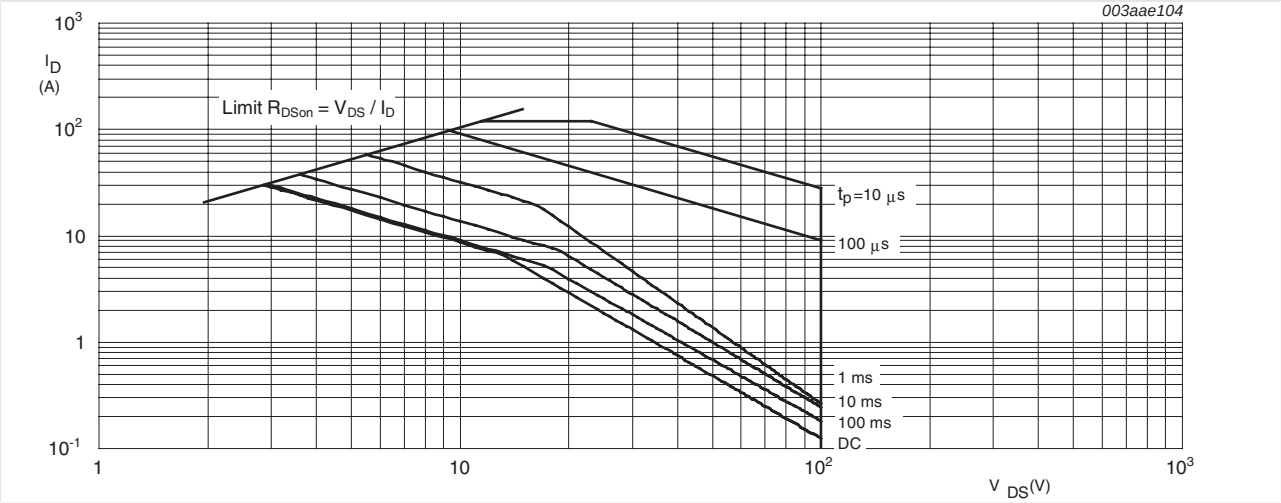
$V_{GS} \geq 10$ V

Fig 1. Continuous drain current as a function of mounting base temperature



$$P_{der} = \frac{P_{tot}}{P_{tot(25°C)}} \times 100\,\%$$

Fig 2. Normalized total power dissipation as a function of mounting base temperature



$T_{mb} = 25\,°C$; I_{DM} is single pulse

Fig 3. Safe operating area; continuous and peak drain currents as a function of drain-source voltage

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j\text{-}mb)}$	thermal resistance from junction to mounting base	see Figure 4	-	0.9	1.7	K/W
$R_{th(j\text{-}a)}$	thermal resistance from junction to ambient	vertical in free air	-	50	-	K/W

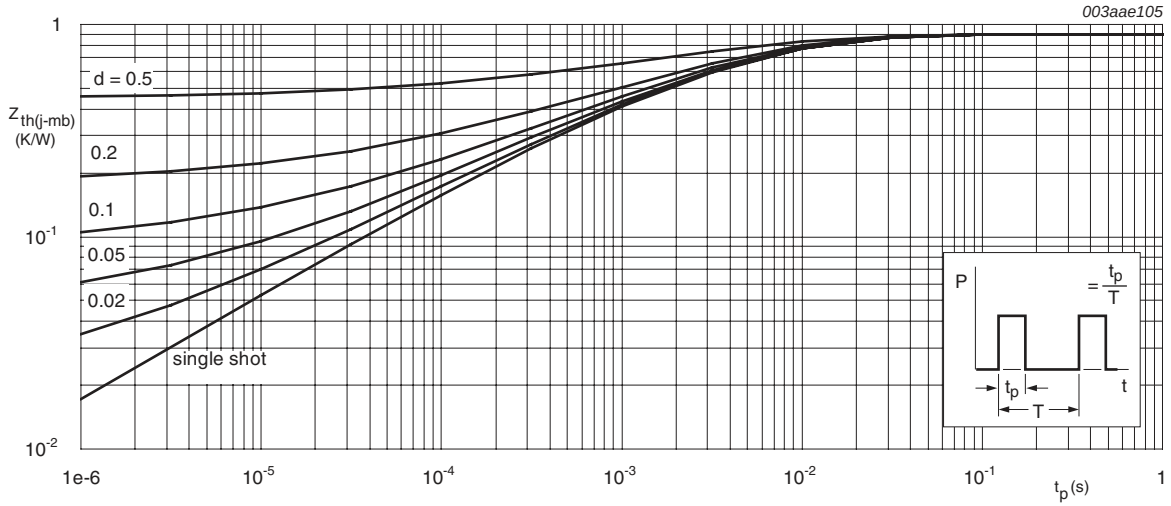


Fig 4. Transient thermal impedance from junction to mounting base as a function of pulse duration; typical values

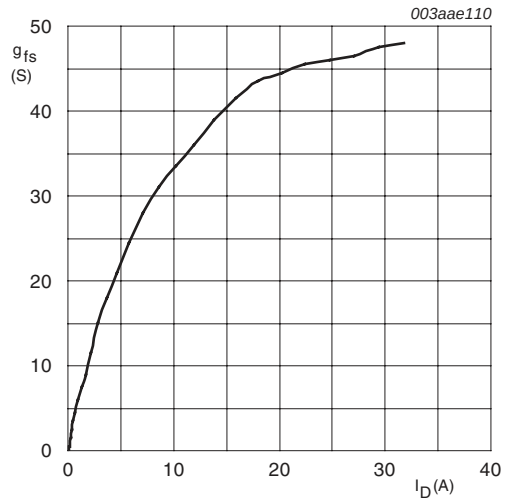
6. Characteristics

Table 6. Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Static characteristics						
$V_{(BR)DSS}$	drain-source breakdown voltage	I_D = 0.25 mA; V_{GS} = 0 V; T_j = -55 °C	90	-	-	V
		I_D = 0.25 mA; V_{GS} = 0 V; T_j = 25 °C	100	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	I_D = 1 mA; V_{DS} = V_{GS}; T_j = 175 °C; see Figure 9	1	-	-	V
		I_D = 1 mA; V_{DS} = V_{GS}; T_j = 25 °C; see Figure 10 and 9	2	3	4	V
		I_D = 1 mA; V_{DS} = V_{GS}; T_j = -55 °C; see Figure 9 and 10	-	-	4.8	V
I_{DSS}	drain leakage current	V_{DS} = 100 V; V_{GS} = 0 V; T_j = 125 °C	-	-	50	µA
		V_{DS} = 100 V; V_{GS} = 0 V; T_j = 25 °C	-	0.02	1	µA
I_{GSS}	gate leakage current	V_{GS} = 20 V; V_{DS} = 0 V; T_j = 25 °C	-	10	100	nA
		V_{GS} = -20 V; V_{DS} = 0 V; T_j = 25 °C	-	10	100	nA
R_{DSon}	drain-source on-state resistance	V_{GS} = 10 V; I_D = 15 A; T_j = 100 °C; see Figure 11	-	-	62	mΩ
		V_{GS} = 10 V; I_D = 15 A; T_j = 175 °C; see Figure 11	-	82.1	96	mΩ
		V_{GS} = 10 V; I_D = 15 A; T_j = 25 °C; see Figure 16	-	29.3	34.5	mΩ
R_G	internal gate resistance (AC)	f = 1 MHz	-	1	-	Ω
Dynamic characteristics						
$Q_{G(tot)}$	total gate charge	I_D = 15 A; V_{DS} = 50 V; V_{GS} = 10 V; see Figure 12 and 13	-	23.8	-	nC
		I_D = 0 A; V_{DS} = 0 V; V_{GS} = 10 V	-	19	-	nC
Q_{GS}	gate-source charge	I_D = 15 A; V_{DS} = 50 V; V_{GS} = 10 V; see Figure 12 and 13	-	5.5	-	nC
$Q_{GS(th)}$	pre-threshold gate-source charge	I_D = 15 A; V_{DS} = 50 V; V_{GS} = 10 V; see Figure 12	-	3.6	-	nC
$Q_{GS(th-pl)}$	post-threshold gate-source charge		-	1.9	-	nC
Q_{GD}	gate-drain charge	I_D = 15 A; V_{DS} = 50 V; V_{GS} = 10 V; see Figure 12 and 13	-	6.9	-	nC
$V_{GS(pl)}$	gate-source plateau voltage	V_{DS} = 50 V; see Figure 12 and 13	-	4.4	-	V
C_{iss}	input capacitance	V_{DS} = 50 V; V_{GS} = 0 V; f = 1 MHz; T_j = 25 °C; see Figure 14	-	1201	-	pF
C_{oss}	output capacitance		-	94	-	pF
C_{rss}	reverse transfer capacitance		-	61	-	pF
$t_{d(on)}$	turn-on delay time	V_{DS} = 50 V; R_L = 3.3 Ω; V_{GS} = 10 V; $R_{G(ext)}$ = 4.7 Ω; T_j = 25 °C	-	12	-	ns
t_r	rise time		-	10	-	ns
$t_{d(off)}$	turn-off delay time		-	28	-	ns
t_f	fall time		-	9	-	ns

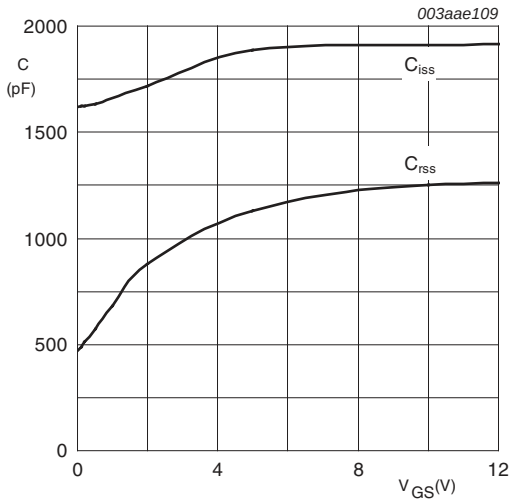
Table 6. Characteristics *...continued*

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Source-drain diode						
V_{SD}	source-drain voltage	I_S = 15 A; V_{GS} = 0 V; T_j = 25 °C; see Figure 17	-	0.85	1.2	V
t_{rr}	reverse recovery time	I_S = 5 A; dI_S/dt = 100 A/µs; V_{GS} = 0 V; V_{DS} = 50 V	-	38	-	ns
Q_r	recovered charge		-	59	-	nC



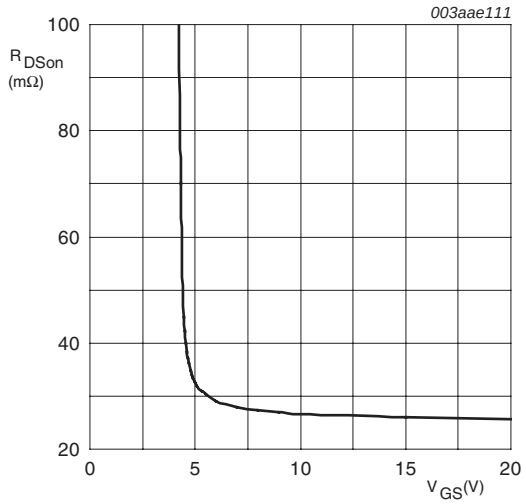
$T_j = 25°C; V_{DS} = 10V$

Fig 5. Forward transconductance as a function of drain current; typical values



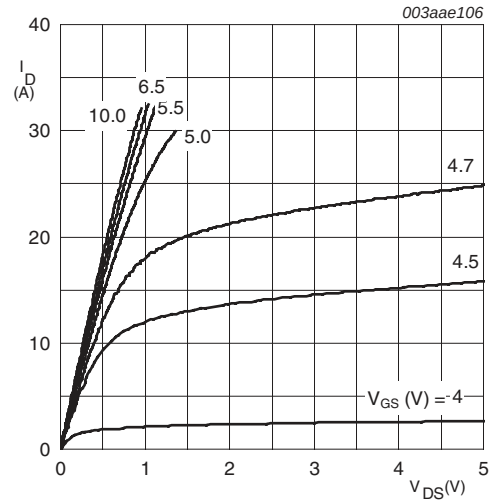
$V_{DS} = 0V; f = 1MH_Z$

Fig 6. Input and reverse capacitances as a function of gate-source voltage; typical values



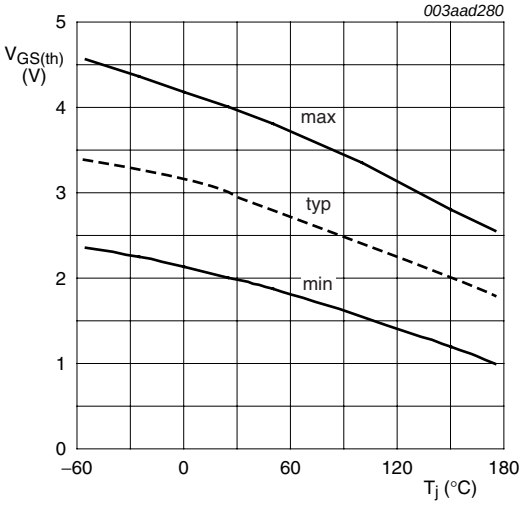
$T_j = 25\,°C; I_D = 5A$

Fig 7. Drain-source on-state resistance as a function of gate-source voltage; typical values



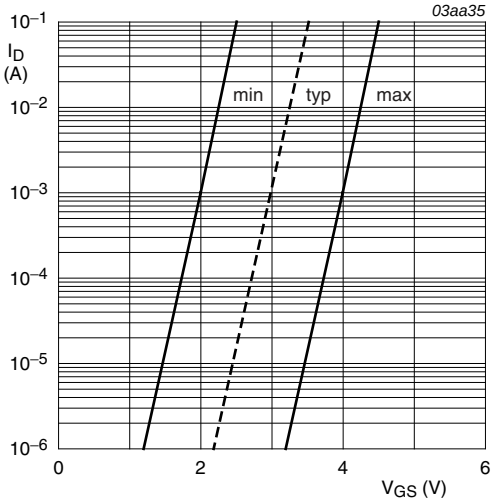
$T_j = 25°C; t_p = 300\mu S$

Fig 8. Output characteristics: drain current as a function of drain-source voltage; typical values



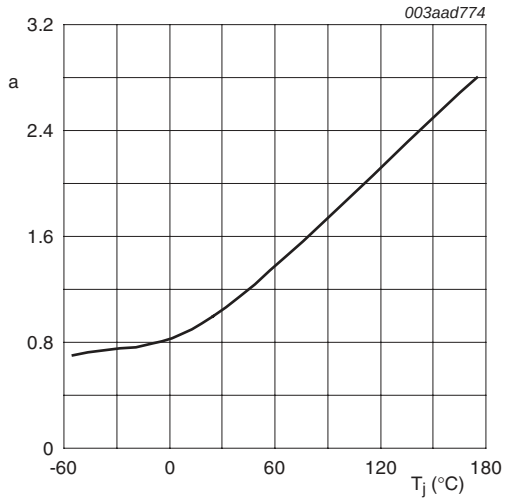
$I_D = 1\ \text{mA};\ V_{DS} = V_{GS}$

Fig 9. Gate-source threshold voltage as a function of junction temperature



$T_j = 25\,°C; V_{DS} = 5V$

Fig 10. Sub-threshold drain current as a function of gate-source voltage



$$a = \frac{R_{DSon}}{R_{DSon(25\,°C)}}$$

Fig 11. Normalized drain-source on-state resistance factor as a function of junction temperature

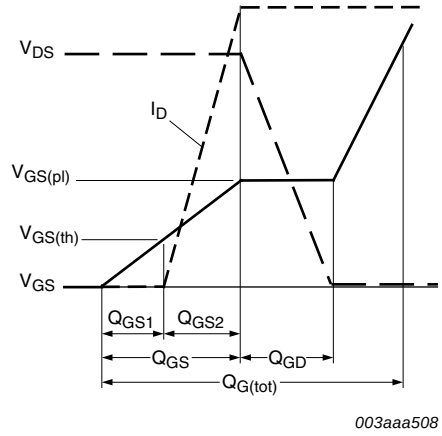
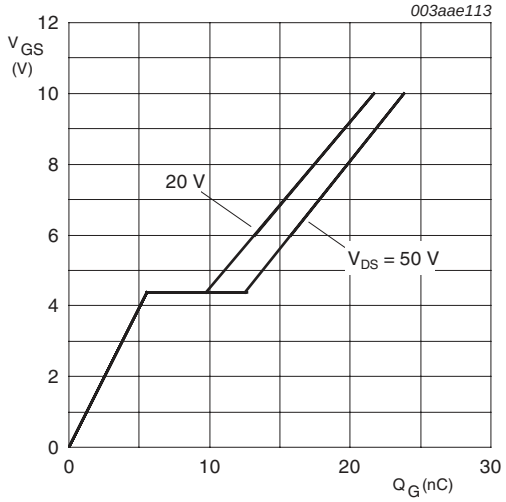
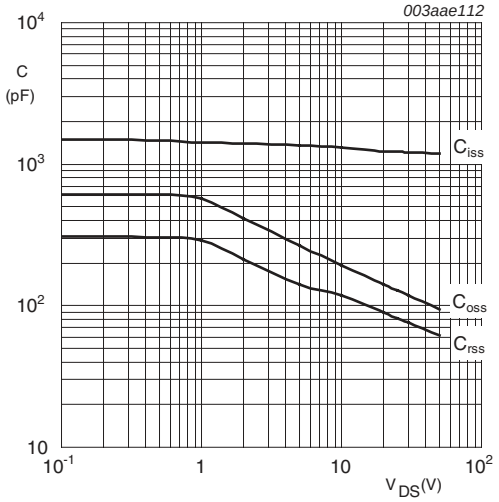


Fig 12. Gate charge waveform definitions



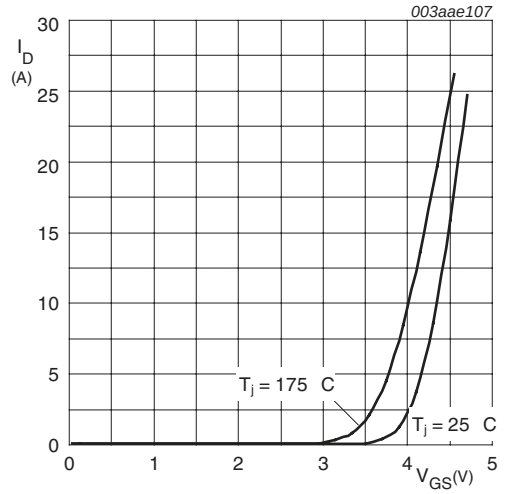
$T_j = 25°C; I_D = 15A$

Fig 13. Gate-source voltage as a function of gate charge; typical values



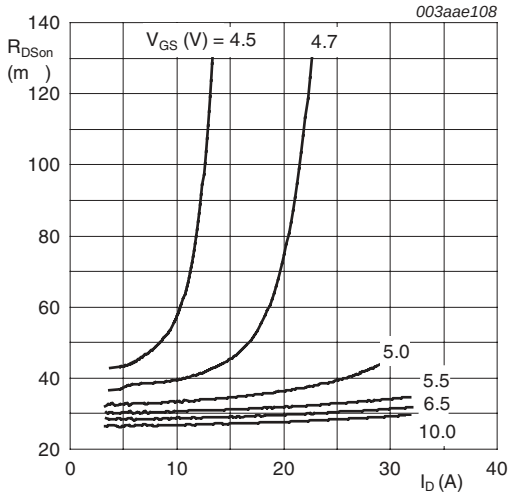
$V_{GS} = 0V; F = 1MH_Z$

Fig 14. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values



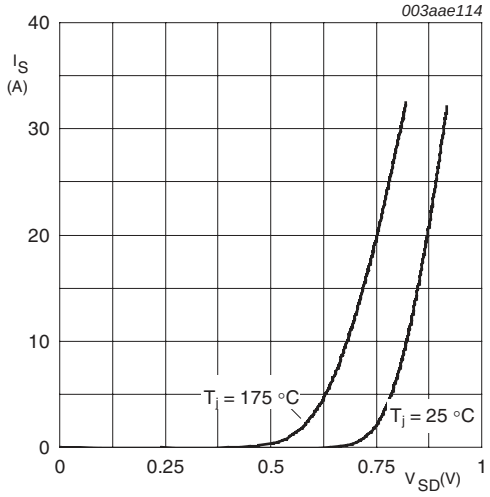
$T_j = 25°C; V_{DS} = 15V$

Fig 15. Transfer characteristics: drain current as a function of gate-source voltage; typical values



$T_j = 25°C; t_p = 300\mu S$

Fig 16. Drain-source on-state resistance as a function of drain current; typical values

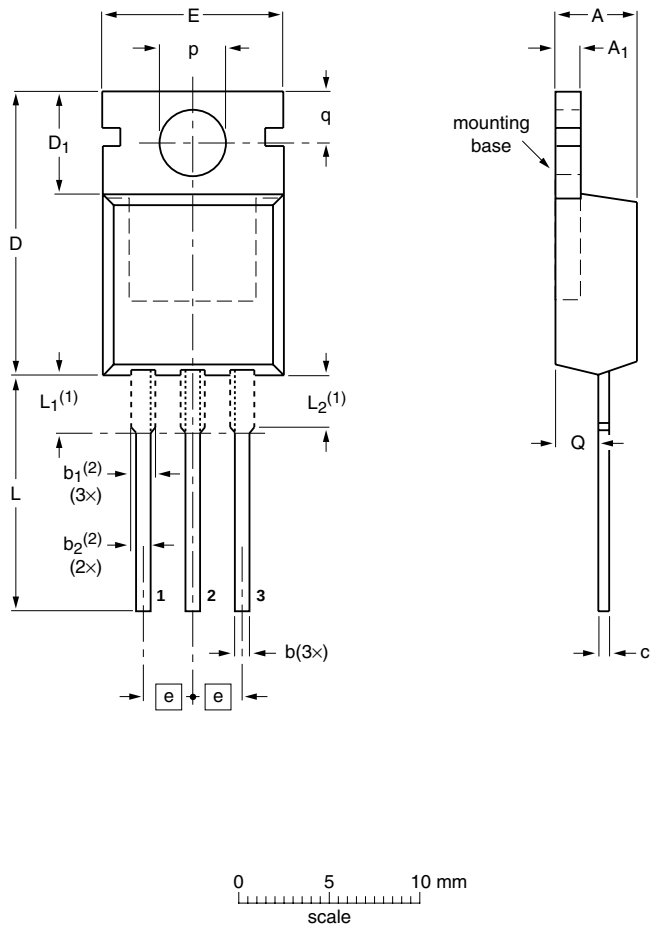


$V_{GS} = 0V$

Fig 17. Source (diode forward) current as a function of source-drain (diode forward) voltage; typical values

7. Package outline

Plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB **SOT78**



DIMENSIONS (mm are the original dimensions)

UNIT	A	A_1	b	b_1(2)	b_2(2)	c	D	D_1	E	e	L	L_1(1)	L_2(1) max.	p	q	Q
mm	4.7 4.1	1.40 1.25	0.9 0.6	1.6 1.0	1.3 1.0	0.7 0.4	16.0 15.2	6.6 5.9	10.3 9.7	2.54	15.0 12.8	3.30 2.79	3.0	3.8 3.5	3.0 2.7	2.6 2.2

Notes
1. Lead shoulder designs may vary.
2. Dimension includes excess dambar.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT78		3-lead TO-220AB	SC-46			~~08-04-23~~ 08-06-13

Fig 18. Package outline SOT78 (TO-220AB)

8. Revision history

Table 7. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PSMN034-100PS_2	20100301	Objective data sheet	-	PSMN034-100PS_1
Modifications:	• Various changes to content.			
PSMN034-100PS_1	20100218	Objective data sheet	-	-

9. Legal information

9.1 Data sheet status

Document status [1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nexperia.com.

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11. Contents

1 Product profile 1
1.1 General description 1
1.2 Features and benefits 1
1.3 Applications 1
1.4 Quick reference data 1
2 Pinning information 2
3 Ordering information 2
4 Limiting values 3
5 Thermal characteristics 5
6 Characteristics 6
7 Package outline 11
8 Revision history 12
9 Legal information 13
9.1 Data sheet status 13
9.2 Definitions 13
9.3 Disclaimers 13
9.4 Trademarks 14
10 Contact information 14

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Date of release: 01 March 2010